

# FOD815 Series 4-Pin High Operating Temperature Photodarlington Optocoupler

### Features

- Applicable to Pb-free IR reflow soldering
- Compact 4-pin package
- High current transfer ratio: 600% minimum
- C-UL, UL, and VDE approved
- High input-output isolation voltage of 5000Vrms
- Higher operating temperature (versus H11B815)

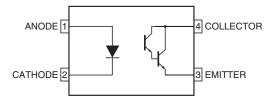
## Applications

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs

## Description

The FOD815 consists of a gallium arsenide infrared emitting diode, driving a silicon photodarlington output in a 4-pin dual in-line package.

## **Functional Block Diagram**





## **Absolute Maximum Ratings** ( $T_A = 25^{\circ}C$ Unless otherwise specified.)

Symbol	Parameter	Value	Units
TOTAL DEVIC	E		
T <sub>STG</sub>	Storage Temperature	-55 to +125	°C
T <sub>OPR</sub>	Operating Temperature	-30 to +105	°C
T <sub>SOL</sub>	Lead Solder Temperature	260 for 10 sec	°C
P <sub>TOT</sub>	Total Power Dissipation	200	mW
INPUT			
١ <sub>F</sub>	Forward Current	50	mA
Р	Power Dissipation	70	mW
OUTPUT			
V <sub>CEO</sub>	Collector-Emitter Voltage	35	V
V <sub>ECO</sub>	Emitter-Collector Voltage	6	V
۱ <sub>C</sub>	Collector Current	80	mA
P <sub>C</sub>	Collector Power Dissipation	150	mW

May 2006

## **Electrical Characteristics** ( $T_A = 25^{\circ}C$ Unless otherwise specified.)

### **Individual Component Characteristics**

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit	
INPUT	INPUT						
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 20mA	-	1.2	1.4	V	
Ct	Terminal Capacitance	V = 0, f = 1kHz	-	50	250	pF	
OUTPUT	OUTPUT						
I <sub>CEO</sub>	Collector Dark Current	$V_{CE} = 10V, I_F = 0$	-	_	1	μA	
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 0.1 {\rm mA}, \ I_{\rm F} = 0$	35	-	-	V	
BV <sub>ECO</sub>	Emitter-Collector Breakdown Voltage	$I_{E} = 10 \mu A, I_{F} = 0$	6	_	_	V	

## Transfer Characteristics ( $T_A = 25^{\circ}C$ Unless otherwise specified.)

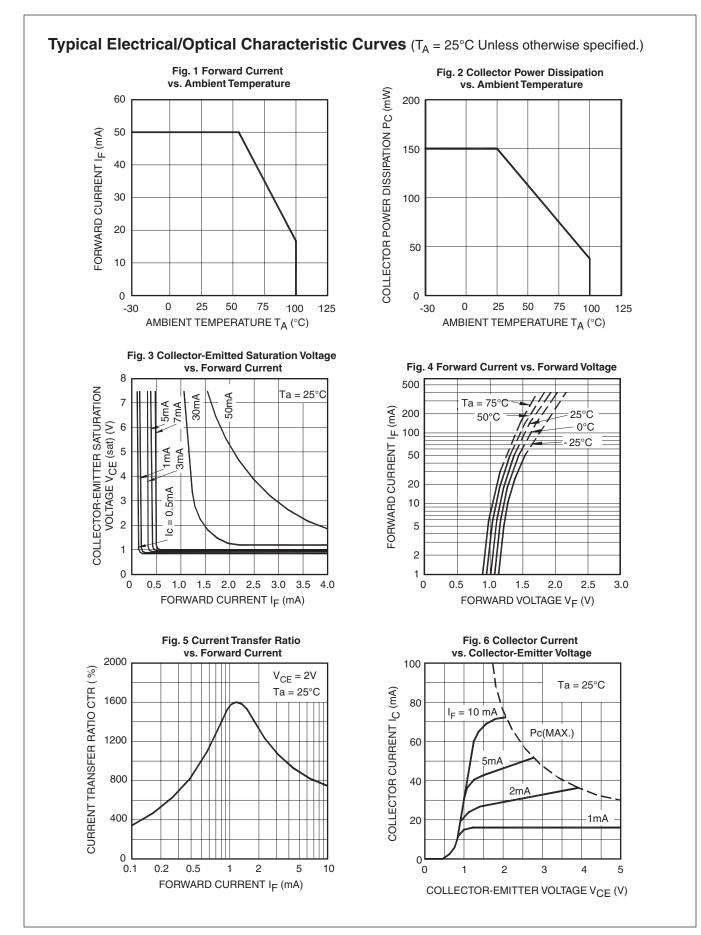
Symbol	DC Characteristic	Test Conditions	Min.	Тур.	Max.	Unit
Ι <sub>C</sub>	Collector Current	$I_F = 1 \text{mA}, V_{CE} = 2 \text{V}$	6	-	75	mA
CTR	Current Transfer Ratio <sup>(1)</sup>		600	-	7,500	%
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>F</sub> = 20mA, I <sub>C</sub> = 5mA	_	0.8	1	V
f <sub>C</sub>	Cut-Off Frequency	$V_{CE}$ = 5V, $I_C$ = 2mA, $R_L$ = 100 $\Omega$ , -3dB	1	6	_	KHz
t <sub>r</sub>	Response Time (Rise)	$V_{CE} = 2 \text{ V}, \text{ I}_{C} = 10 \text{mA}, \text{ R}_{L} = 100 \Omega$	_	60	300	μs
t <sub>f</sub>	Response Time (Fall)		_	53	250	μs

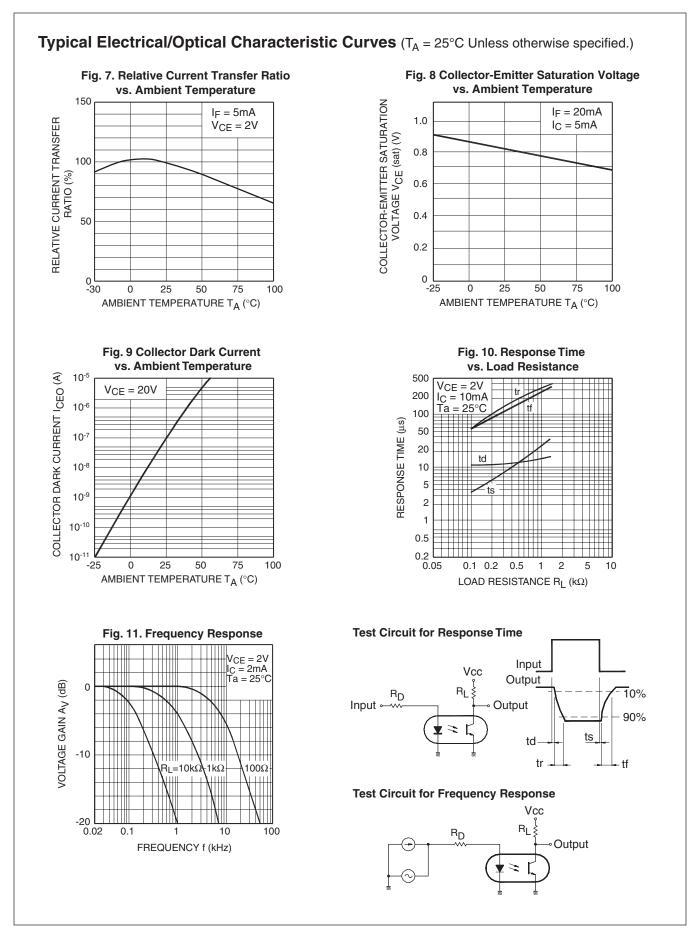
### **Isolation Characteristics**

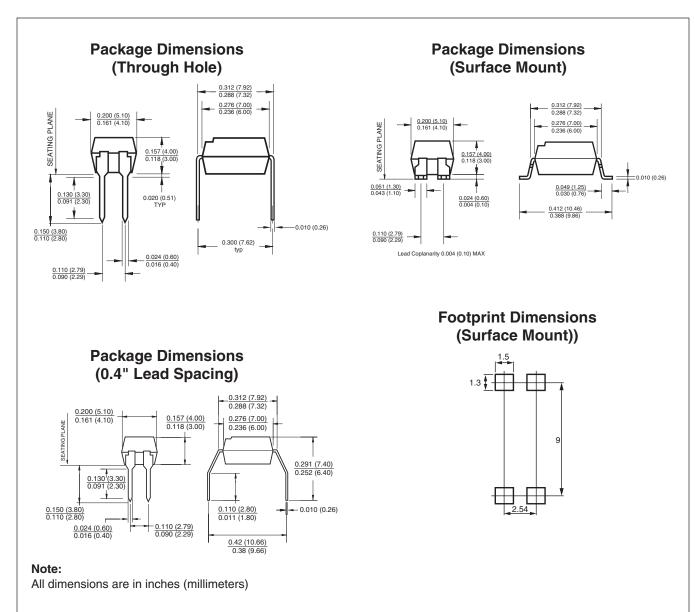
Symbol	Characteristic	Test Conditions	Min.	Тур.	Max.	Units
V <sub>ISO</sub>	Input-Output Isolation Voltage	$f=60Hz,t=1min,I_{I\text{-}O}\leq 2\mu A$	5000	-	_	Vac(rms)
R <sub>iso</sub>	Isolation Resistance	DC500V 40~60% R.H.	5x10 <sup>10</sup>	1x10 <sup>11</sup>	-	Ω
C <sub>f</sub>	Floating Capacitance	V = 0, f = 1MHz	_	0.6	1	pF

### Note:

1. Current Transfer Ratio (CTR) =  $I_C/I_F \times 100\%$ .



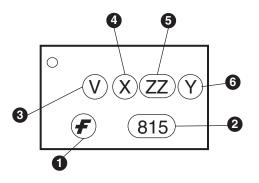




## **Ordering Information**

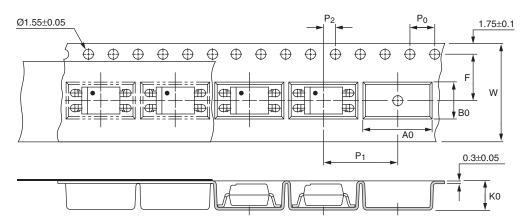
Option	Order Entry Identifier	Description
S	.S	Surface Mount Lead Bend
SD	.SD	Surface Mount; Tape and reel
W	.W	0.4" Lead Spacing
300	.300	VDE Approved
300W	.300W	VDE Approved, 0.4" Lead Spacing
3S	.3S	VDE Approved, Surface Mount
3SD	.3SD	VDE Approved, Surface Mount, Tape & Reel

## **Marking Information**



Definitions				
1	Fairchild logo			
2	Device number			
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)			
4	One digit year code			
5	Two digit work week ranging from '01' to '53'			
6	Assembly package code			

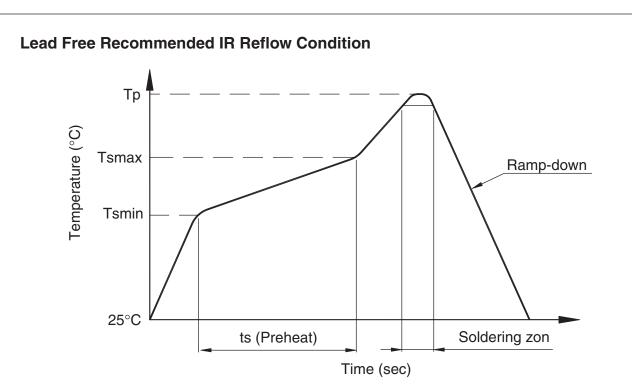
## **Carrier Tape Specifications**



### Note:

All dimensions are in millimeters.

Description	Symbol	Dimensions in mm (inches)
Tape wide	W	16 ± 0.3 (.63)
Pitch of sprocket holes	P <sub>0</sub>	4 ± 0.1 (.15)
Distance of compartment	F P <sub>2</sub>	7.5 ± 0.1 (.295) 2 ± 0.1 (.079)
Distance of compartment to compartment	P <sub>1</sub>	12 ± 0.1 (.472)
Compartment	A0	10.45 ± 0.1 (.411)
	B0	5.30 ± 0.1 (.209)
	K0	4.25 ± 0.1 (.167)



Profile Feature	Pb-Sn solder assembly	Lead Free assembly
Preheat condition (Tsmin-Tsmax / ts)	100°C ~ 150°C 60 ~ 120 sec	150°C ~ 200°C 60 ~120 sec
Melt soldering zone	183°C 60 ~ 120 sec	217°C 30 ~ 90 sec
Peak temperature (Tp)	240 +0/-5°C	260 +0/-5°C
Ramp-down rate	6°C/sec max.	6°C/sec max.

## **Recommended Wave Soldering condition**

Profile Feature	For all solder assembly
Peak temperature (Tp)	Max 260°C for 10 sec

### TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

FAST® ACEx™ ActiveArray™ FASTr™ FPS™ Bottomless™ Build it Now™ FRFET™ CoolFET™ GlobalOptoisolator™ *CROSSVOLT*™ GTO™ DOME™ HiSeC™ I<sup>2</sup>C™ **EcoSPARK™** E<sup>2</sup>CMOS™ i-Lo™ EnSigna™ ImpliedDisconnect<sup>™</sup> FACT™ IntelliMAX™ FACT Quiet Series™ Across the board. Around the world.™ The Power Franchise<sup>®</sup> Programmable Active Droop™

ISOPLANAR<sup>™</sup> LittleFET<sup>™</sup> MICROCOUPLER<sup>™</sup> MicroFET<sup>™</sup> MicroPak<sup>™</sup> MICROWIRE<sup>™</sup> MSX<sup>™</sup> MSXPro<sup>™</sup> OCX<sup>™</sup> OCX<sup>™</sup> OCXPro<sup>™</sup> OPTOLOGIC<sup>®</sup> OPTOPLANAR<sup>™</sup> PACMAN<sup>™</sup> POP<sup>™</sup> Power247<sup>™</sup>

PowerEdge<sup>™</sup> PowerSaver<sup>™</sup> PowerTrench<sup>®</sup> QFET<sup>®</sup> QS<sup>™</sup> QT Optoelectronics<sup>™</sup> Quiet Series<sup>™</sup> RapidConfigure<sup>™</sup> RapidConfigure<sup>™</sup> RapidConnect<sup>™</sup> µSerDes<sup>™</sup> ScalarPump<sup>™</sup> SILENT SWITCHER<sup>®</sup> SMART START<sup>™</sup> SPM<sup>™</sup> Stealth<sup>™</sup> SuperFET™ SuperSOT™-3 SuperSOT™-6 SuperSOT™-7 SyncFET™ TCM™ TinyLogic<sup>®</sup> TINYOPTO™ TruTranslation™ UHC™ UniFET™ UltraFET<sup>®</sup> VCX™ Wire™

### DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILDIS WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

### LIFE SUPPORT POLICY

FAIRCHILDÍS PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

#### As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

### PRODUCT STATUS DEFINITIONS Definition of Terms

Product Status	Definition
Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.
	Formative or In Design First Production Full Production